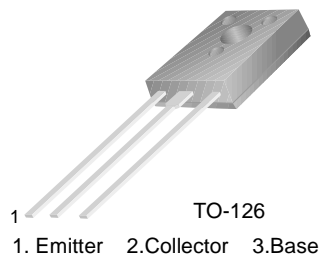


# KSA1142

KSA1142

## Audio Frequency Power Amplifier High Frequency Power Amplifier

- Complement to KSC2682



## PNP Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_C=25^{\circ}\text{C}$ unless otherwise noted

| Symbol    | Parameter  | Ratings    | Units              |
|-----------|--|------------|--------------------|
| $V_{CBO}$ | Collector-Base Voltage                             | - 180      | V                  |
| $V_{CEO}$ | Collector-Emitter Voltage                          | - 180      | V                  |
| $V_{EBO}$ | Emitter-Base Voltage                               | - 5        | V                  |
| $I_C$     | Collector Current                                  | - 100      | mA                 |
| $P_C$     | Collector Dissipation ( $T_a=25^{\circ}\text{C}$ ) | 1.2        | W                  |
| $P_C$     | Collector Dissipation ( $T_C=25^{\circ}\text{C}$ ) | 8          | W                  |
| $T_J$     | Junction Temperature                               | 150        | $^{\circ}\text{C}$ |
| $T_{STG}$ | Storage Temperature                                | - 55 ~ 150 | $^{\circ}\text{C}$ |

### Electrical Characteristics $T_C=25^{\circ}\text{C}$ unless otherwise noted

| Symbol                 | Parameter                              | Test Condition   | Min.      | Typ.       | Max.  | Units         |
|------------------------|--|--|-----------|------------|-------|---------------|
| $I_{CBO}$              | Collector Cut-off Current              | $V_{CB} = -180\text{V}, I_E = 0$   |           |            | - 1   | $\mu\text{A}$ |
| $I_{EBO}$              | Emitter Cut-off Current                | $V_{EB} = -3\text{V}, I_C = 0$   |           |            | - 1   | $\mu\text{A}$ |
| $h_{FE1}$<br>$h_{FE2}$ | * DC Current Gain                      | $V_{CE} = -5\text{V}, I_C = -1\text{mA}$<br>$V_{CE} = -5\text{V}, I_C = -10\text{mA}$  | 90<br>100 | 200<br>200 | 320   |               |
| $V_{CE(sat)}$          | * Collector-Emitter Saturation Voltage | $I_C = -50\text{mA}, I_B = -5\text{mA}$  |           | - 0.16     | - 0.5 | V             |
| $V_{BE(sat)}$          | * Base-Emitter Saturation Voltage      | $I_C = -50\text{mA}, I_B = -5\text{mA}$  |           | - 0.8      | - 1.5 | V             |
| $f_T$                  | Current Gain Bandwidth Product         | $V_{CE} = -10\text{V}, I_C = -20\text{mA}$   |           | 180        |       | MHz           |
| $C_{ob}$               | Output Capacitance                     | $V_{CB} = -10\text{V}, I_E = 0, f=1\text{MHz}$   |           | 4.5        | 7     | pF            |
| NF                     | Noise Figure                           | $V_{CE} = -10\text{V}, I_C = -1\text{mA}$<br>$R_S = 10\text{k}\Omega, f = 1\text{MHz}$ |           | 4          |       | dB            |

\* Pulse Test:  $PW \leq 350\mu\text{s}$ , Duty Cycle  $\leq 2\%$  Pulsed

### $h_{FE}$ Classification

| Classification | O         | Y         |
|----------------|-----------|-----------|
| $h_{FE2}$      | 100 ~ 200 | 160 ~ 320 |

# Typical Characteristics

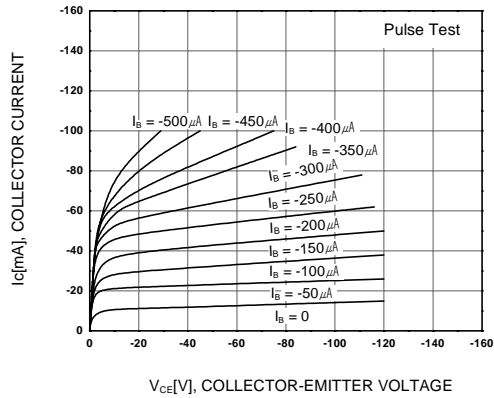


Figure 1. Static Characteristic

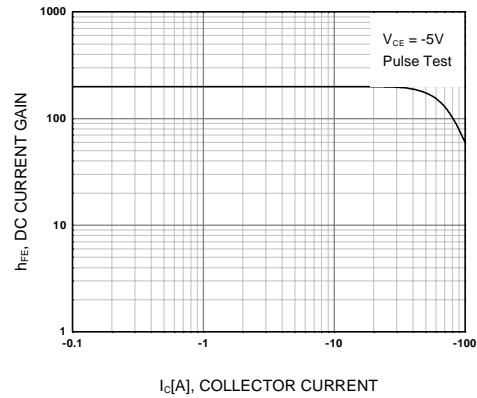


Figure 2. DC current Gain

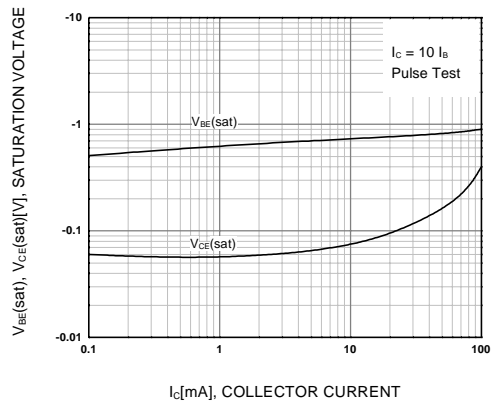


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

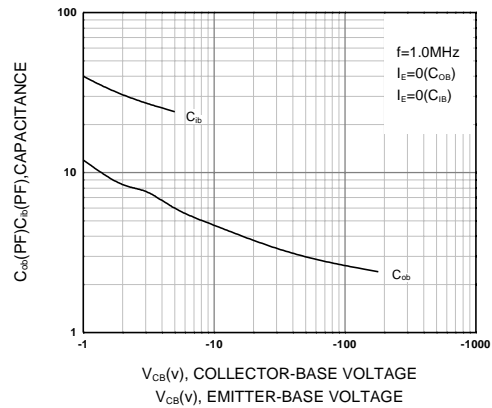


Figure 4. Collector Output Capacitance

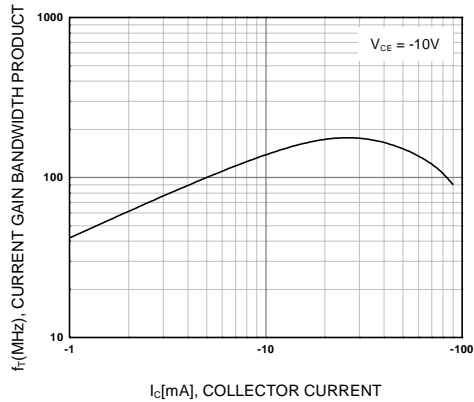


Figure 5. Current Gain Bandwidth Product

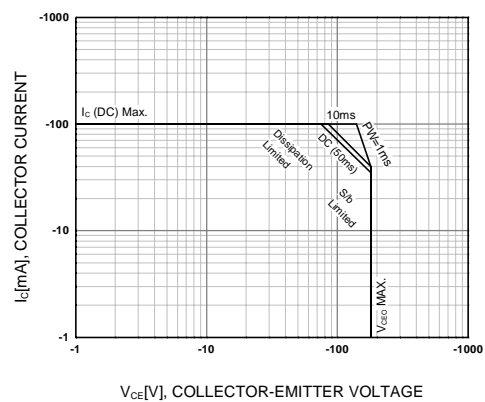


Figure 6. Safe Operating Area

## Typical Characteristics (Continued)

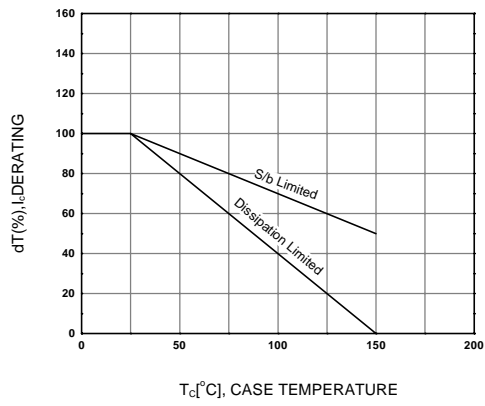


Figure 7. Derating Curve of Safe Operating Areas

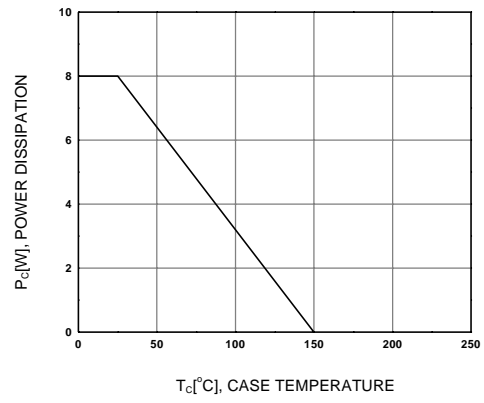
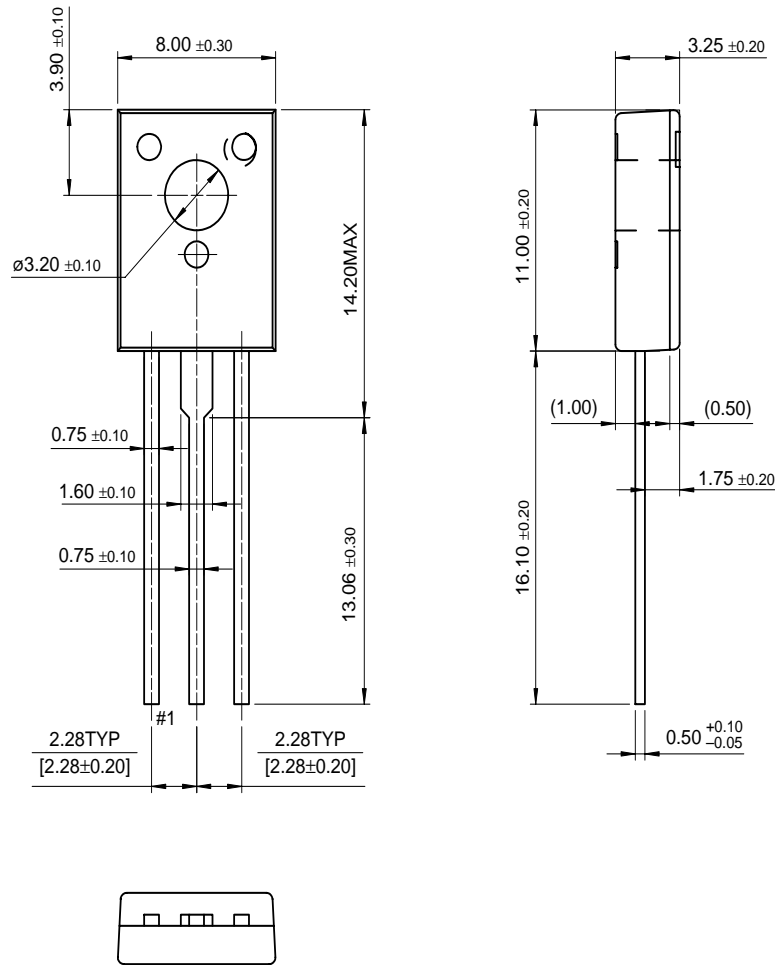


Figure 8. Power Derating

# Package Dimensions

## TO-126



Dimensions in Millimeters

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